

1SS294

PRV : 45 Volts
Io : 100 mA

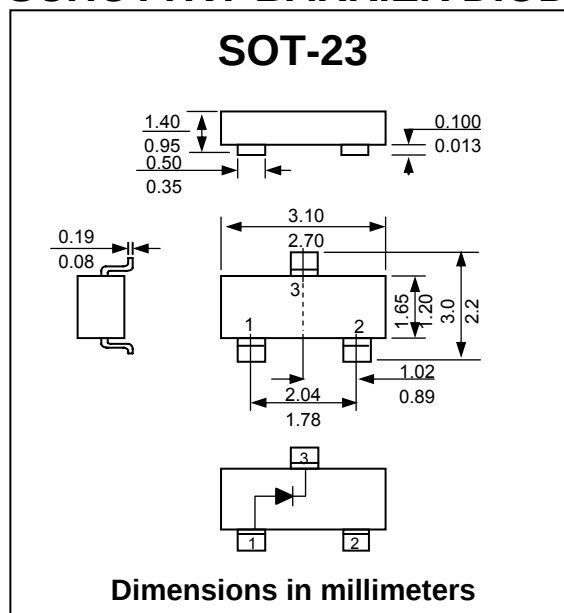
FEATURES :

- * Small surface mounting type
- * Low forward voltage
- * Low reverse current
- * Pb / RoHS Free

MECHANICAL DATA :

- * Case : SOT-23 plastic Case
- * Marking Code : " XM "

SILICON EPITAXIAL PLANAR SCHOTTKY BARRIER DIODE



MAXIMUM RATINGS AND THERMAL CHARACTERISTICS (Ta =25 °C)

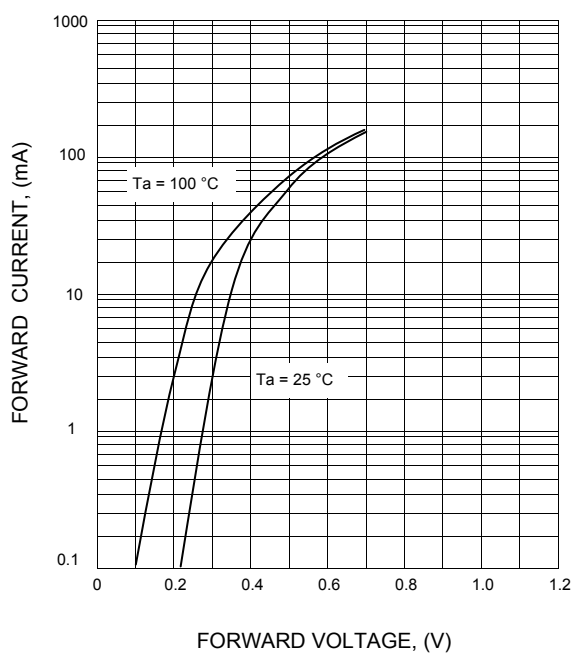
Parameter	Symbol	Value	Unit
Maximum Peak Reverse Voltage	V_{RM}	45	V
Reverse Voltage	V_R	40	V
Maximum Peak Forward Current	I_{FM}	300	mA
Average Forward Current	$I_{F(AV)}$	100	mA
Power Dissipation	P_D	150	mW
Junction Temperature	T_J	125	°C
Storage Temperature Range	T_{STG}	-55 to +125	°C

ELECTRICAL CHARACTERISTICS (Ta =25 °C)

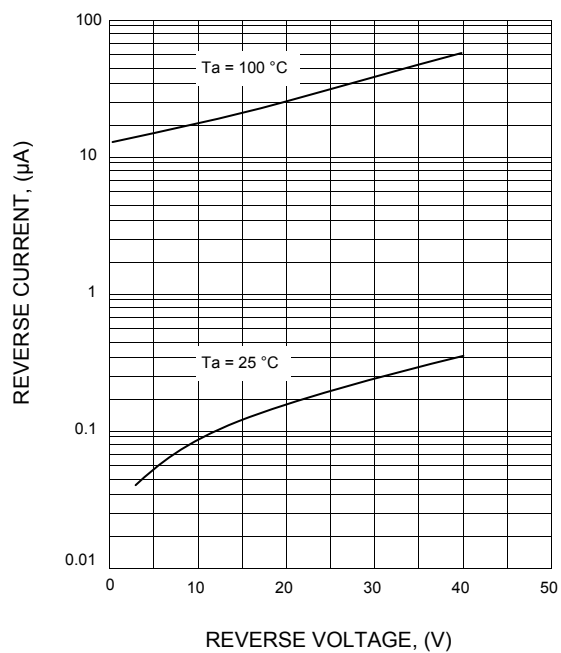
Parameter	Test Condition	Symbol	Min.	Max.	Unit
Forward Voltage	$I_F = 100 \text{ mA}$	V_F	-	0.6	V
Reverse Current	$V_R = 40 \text{ V}$	I_R	-	5	μA
Total Capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$	C_T	-	25	pF

RATINGS AND CHARACTERISTIC CURVES (1SS294)

**FIG.1 - FORWARD CURRENT VS.
FORWARD VOLTAGE**



**FIG.2 - REVERSE CURRENT VS.
REVERSE VOLTAGE**



**FIG.3 - TOTAL CAPACITANCE VS.
REVERSE VOLTAGE**

